X-ray Detectors: State-of-the-art & Future Possibilities

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Cornell University

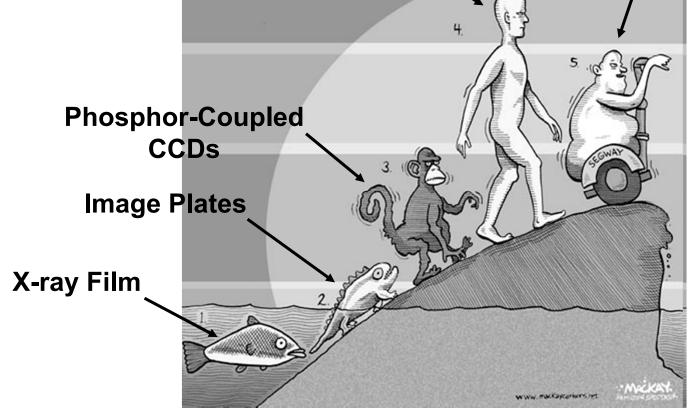
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Evolution of Imaging Synchrotron X-ray Detectors

Direct-Detection Semiconductors

Intelligent Direct-Detection Semiconductors



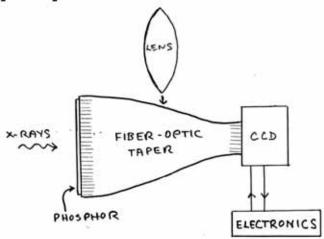


What is feasible in the next decade, given sufficient R&D?

Less prevalent imaging detectors are omitted for sake of time.



Limitations arise from fundamental physical properties of detector parts



Phosphor: settled powder or single crystal garnet

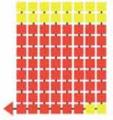
- Speed (msec to μs) vs. efficiency, even for single snapshots
- Resolution vs. efficiency

Light relay system: fiber optics bundle or lens

- Fiber optics limit resolution to several microns
- Lenses have higher resolution, but limit dynamic range

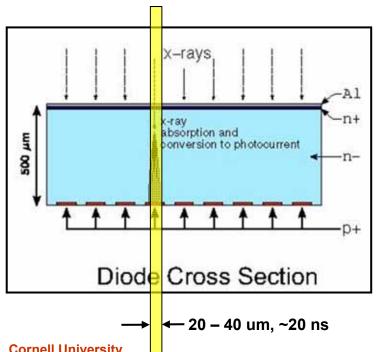
CCD

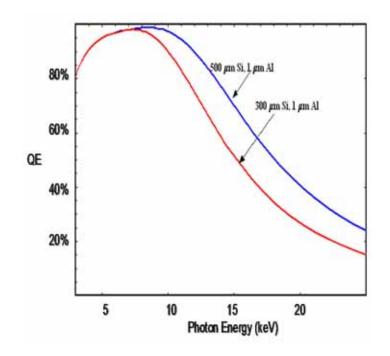
• Serial nature of readout limits frame time Normal depletion thickness is only a few microns



Direct Detection in Silicon

- Si is a superb x-ray to electrical signal converter.
- @ 10 keV, radius of e-h cloud ~ 1 micron.
- Number e-h pairs, N_{eh} : $E_{x-ray}/3.65$ eV
- $\sigma(N_{eh})/N_{eh} = \sqrt{F/N_{eh}}$, where $F \equiv \text{Fano Factor} = 0.1$.
- 10 keV yields N_{eh} = 2740 ± 20. (ΔE = ±3.65 x 20 eV = 146 eV width)



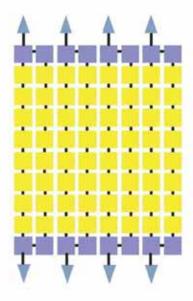


Cornell University
Physics Department & CHESS



CCD output configuration

- CCDs are intrinsically slow
 - Single output CCD
 - Column parallel CCD
 - Almost column parallel CCD
- LBNL FCCD
 - Multiple outputs (ex.48 per side)
 - Faster outputs (ex.1MHz)
 - 200 fps



September 21, 2010

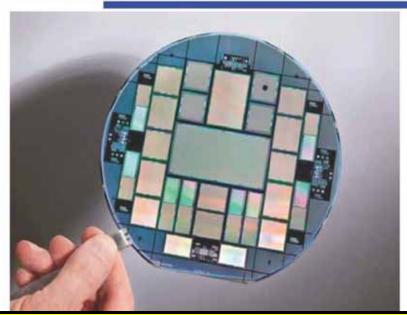
D. Doering, LBNL @ SRI 2010 Detector workshop

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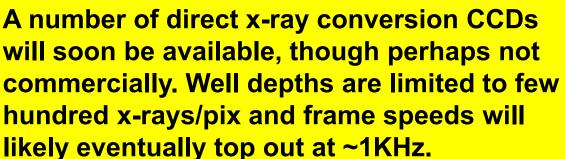


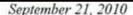


(New) R&D CCD - 1k Frame Store



- 30 x 30 um pixel
- 1920x960 pixels (8 times the area of cFCCD)
- Thick 200-650um
- 200fps
- Data volume ~ 400MB/s (HD 250GB -> ~10 min)





D. Doering, LBNL @ SRI 2010 Detector workshop





Semiconductors

Physical characteristics of the semiconductors

Semi- conductor	ρ [g/cm ³]	Z	$E_{ m gap}$ [eV]	ε [eV]	T _{working} [K]	K-edge [keV]	$\rho_{\rm e}$ $[\Omega \text{ cm}]$	$\mu_{e,h} \tau_{e,h}$ [cm ² /V]
Si	2.33	14	1.12	3.6 [1]	300	1.8	≈10 ³	0.42, 0.22
Ge	5.33	32	0.67	2.9[3]	77	11.1	$\approx 10^2$	0.72, 0.84
GaSe	4.55	- 31, 34	2.03	4.5 [4]	300	10.3, 12.6		$10^{-7}, 10^{-7}$ $1.5 \times 10^{-6}, 2.5 \times 10^{-6}$
InP	4.78	49, 15	1.30	4.2 [6]	300	27.9, 2.1	$\approx 10^7$	$4.8 \times 10^{-6}, \leq 10^{-7}$
CdS	4.84	48, 16	2.60	7.3 [15]	300	26.7, 2.4		
GaAs	5.32	- 31, 33	1.43	4.3 [3]	300	10.3, 11.8	. ≈10 ⁷	$8.6 \times 10^{-6}, 4.0 \times 10^{-7}$ $8.6 \times 10^{-5}, 4.0 \times 10^{-6}$
InSb	5.77	49, 51	0.20	0.6 [15]	4	27.9, 30.4		10^{-5} , 7.5×10^{-6}
CdSe	5.80	48, 34	1.73	5.5 a	300	26.7, 12.6		2.0×10^{-5} , 1.5×10^{-6}
CdTe	6.20	48, 52	1.44	4.7 [3]	300	26.7, 31.8	$\approx 10^9$	2.0×10^{-3} , 4.0×10^{-4}
PbI ₂	6.20	82, 53	2.55	7.7 a	300	88.0, 33.2	$>10^{13}$	8.0×10^{-6} , 2.0×10^{-7}
HgI ₂	6.40	80, 53	2.13	4.2 [7]	300	83.1, 33.2	10 ¹³	10^{-4} , 10^{-5}
TIBr	7.56	81, 35	2.68	6.5 [18]	300	85.5, 13.5	$\approx 10^{12}$	1.6×10^{-5} , 1.5×10^{-6}

From Bencivelli et al., Nucl. Instr. Meth. Phys. Res. A310 (1991) 210-214

On a decade time scale x-ray sensors of "exotic" semiconductors are feasible, though probably only as bump-bonded sensors. High atomic number materials can extend detection to very hard x-rays.

Basic Pixel Array Detector (PAD)

Diode Detection Layer • Fully depleted, high resistivity X-rays Direct x-ray conversion in Si **Connecting Bumps** • Solder, 1 per pixel **CMOS** Layer Signal processing • Signal storage & output Gives enormous flexibility!

PADs come in two varieties

Photon counting PADs

- Front ends count each x-ray individually. (PILATUS, Medipix)
- Drawback for high-speed imaging: Count-rate limited by electronics to ~10⁶ -10⁷ x-rays/pix/sec.

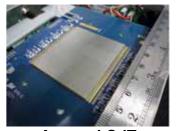


Integrating PADs

- Use an integrating front-end to avoid the count-rate bottleneck.
- Capable of handling enormous count-rate.
- Existing variants include LCLS, ADSC, Acrorad



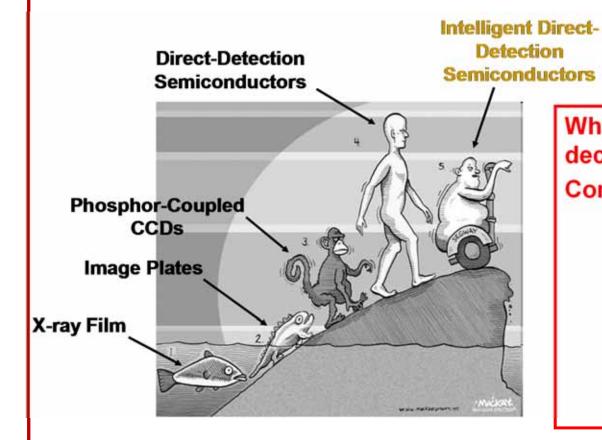
Cornell-SLAC LCLS



Acrorad CdTe

Cornell University

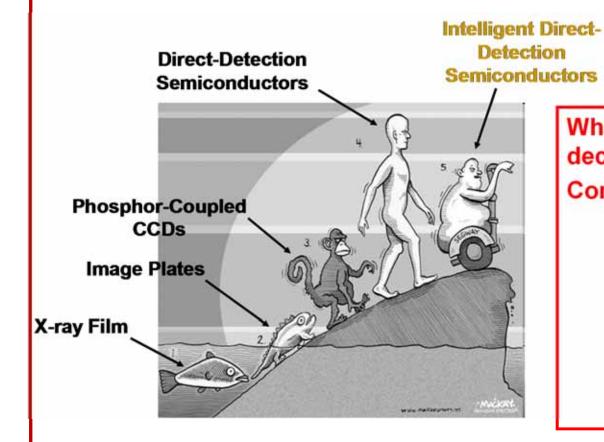
Evolution of Imaging Synchrotron X-ray Detectors



What is feasible in the next decade, given sufficient R&D? Consider:

- Pixel size & complexity
- Spatial resolution
- Time resolution
- Analog dynamic range
- Energy resolution

Evolution of Imaging Synchrotron X-ray Detectors



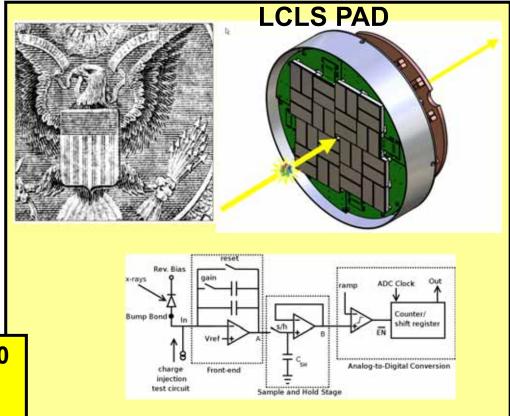
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KECK PAD				
Parameter	Target Value			
Noise	< 0.5 x-ray/pixel/accumulation			
Minimum exposure time	<150 ns for 12-bit imaging			
Capacitor well depth	2000 – 4000 x-rays			
Nonlinearity (% full well)	< 0.2%			
Diode conversion layer	500 μm thick Si			
Number of capacitor wells/pix	8			
Full chip frame time	1 msec/frame, e.g., 8 msec for 8 capacitors			
Radiation lifetime	> 50 Mrad at detector face @ 8 keV			
Pixel size	150 µm on a side, or 128 x 128 pixels per IC			
Detector chip format	2 x 4 chips = 256 x 512 pixels			

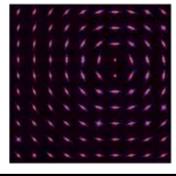
Complexity at the level of 200 – 300 transistors/pixel. 0.25 um process.

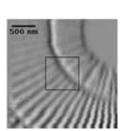
Pixel sizes of 110 & 150 um across.

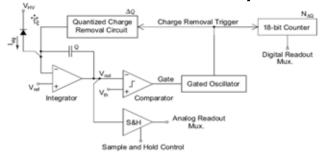


Mixed-Mode PAD (ADSC Collaboration)

PAD Tile Format	128 x 128 pixels
Pixel Size	150 μm x 150 μm
Frame Rate	Up to 1,000 Hz
Read Noise	0.3 X-ray [12 keV] / pix
Well Capacity	2.6 x 10 ⁷ X-ray [12 keV]/pix/frame







3D-ICs based on Silicon-on-Insulator (SOI) Wafers

"...Small prototypes of VIPs are extendable to sizes of 1024×1024 pixels, bearing the actual needs of the application. The top tier contains a gated charge integrator, a single ended AC-coupled offset corrected discriminator with capacitively injected threshold, an analog memory for reference sample, an analog memory for post discriminator sample, a pulse generator for time stamping lock and hit information lock, a receiving part of test-charge injection capacitance and a bonding pad to the detector. The intermediate tier features an analog memory cell for time stamping (distributed voltage ramp), a 7-bit SRAM-like digital time stamping memory with output enable control to read on the same lines on which time ticks in Gray code are distributed. The bottom tier hosts the sparsification system: token propagation logic, wiredOR line access logic for X-line/Y-line of a hit pixel address generator, test-charge injection logic and a peripheral serialization and output part."

This is ~200 transistor level of complexity in 20 um pixel.

From: Deptuch et al, FERMILAB-CONF-10-401-PPD

BOX3

oxide-oxide fusion bond

BOX2

oxide-oxide fusion bond

BOX1

8.4 μm

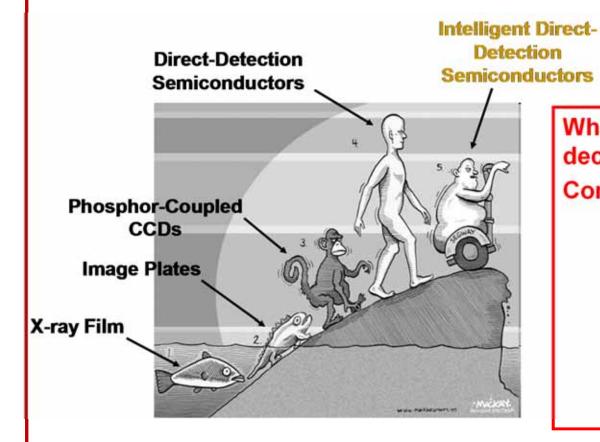
6.2 μm

On a decade time scale pixels with reasonable levels of complexity and 10 – 20um pixel sizes are feasible.

Deptuch et al, FERMILAB-PUB-10-314-ppd



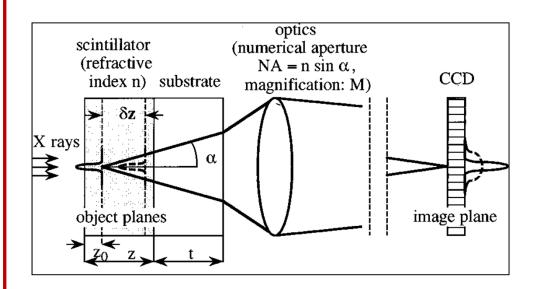
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High Spatial Resolution Using Doped Garnets



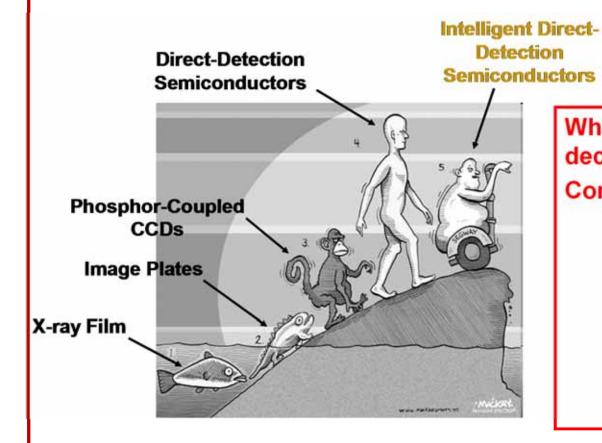
Single crystal YAG:Ce and **GGG:Eu screens with doped** layers microns thick are commercially available (e.g., ESRF; laser vendors).

Present spatial resolutions of ~0.7um are available with reasonable efficiencies. The wavelength of light and photoelectron emission will likely limit this to small digit improvements, at best.



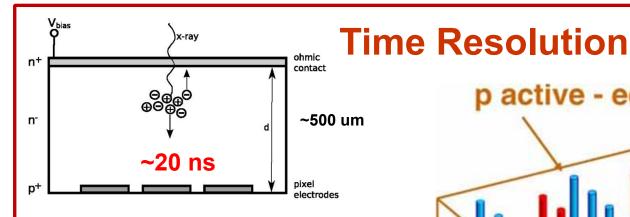
From: Koch at al., J. Opt. Soc. Am. A 15 (1998) 1940

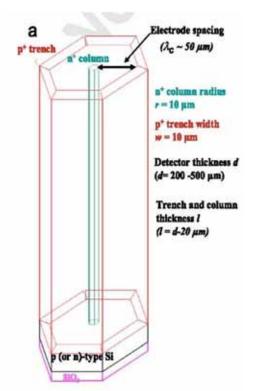
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few ns

using Si

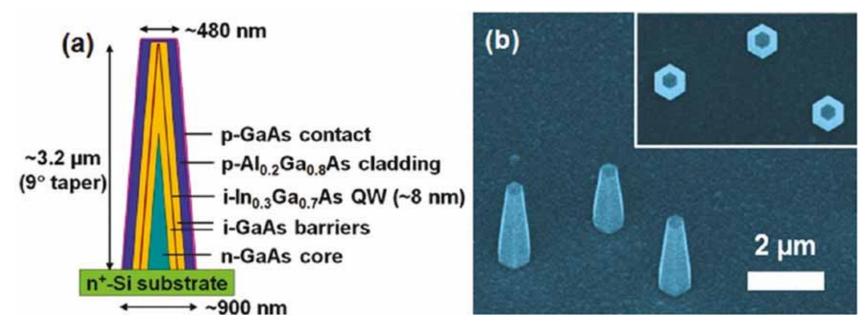
Z. Li, Nucl. Instr. and Meth. A (2011), doi:10.1016/j.nima.2011.05.003

Track Internal 3D electrodes

Parker et al., IEEE Trans. Nucl. Sci. 58 (2011) 404.

3D silicon sensors capable of a few ns response are in advanced R&D. On a decade time scale, use of "exotic" semiconductors and few hundred ps response may be feasible.

Time Resolution: Use Nanopillars



From: Chuang et al., NANO Letters 11 (2011) 385

This is an LED, but they also report on Avalanche Photodiodes (APD)

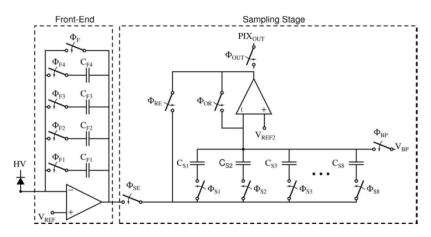
A dense forest of nanopillar APDs are in principle capable of few ps response. With sufficient R&D fill factors of ~25% may become feasible. Readout electronics then become limiting.

Frame Time

Considerations:

- Front-end amplifier settling time.
- Time to transfer data to off-ASIC digital memory. Parallelize!

KECK PAD				
Parameter	Target Value			
Noise	< 0.5 x-ray/pixel/accumulation			
Minimum exposure time	<150 ns for 12-bit imaging			
Capacitor well depth	2000 – 4000 x-rays			
Nonlinearity (% full well)	< 0.2%			
Diode conversion layer	500 μm thick Si			
Number of capacitor wells/pix	8			
Full chip frame time	1 msec/frame, e.g., 8 msec for 8 capacitors			
Radiation lifetime	> 50 Mrad at detector face @ 8 keV			
Pixel size	150 µm on a side, or 128 x 128 pixels per IC			
Detector chip format	2 x 4 chips = 256 x 512 pixels			
Dark current	2 x-rays/pix/sec			



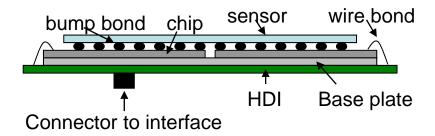
Koerner & Gruner, J. Synchro. Rad. 18 (2011) 157.

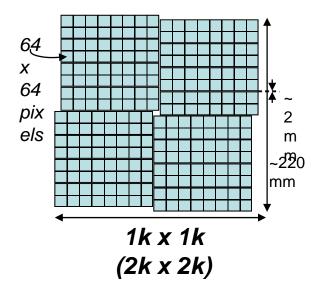
< 150 ns for 12 bit settling shown. Equivalent to ~4000 8 keV x-rays. Faster for fewer bits. A few bits in 10's of ns should be feasible.

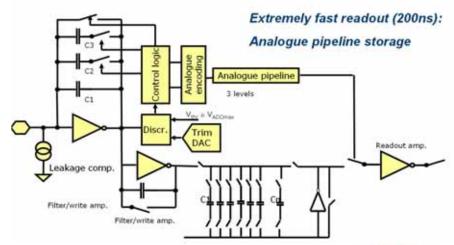
The Adaptive Gain Integrating Pixel Detector

Basic parameters

- •1 Megapixel detector (1k × 1k)
- •200mm × 200mm pixels
- •Flat detector
- •Sensor: Silicon 128 x 512 pixel tiles
- Single shot 2D-imaging
- •5MHz frame rate
- •2 × 10⁴ photons dynamic range
- Adaptive gain switching
- Single photon sensitivity at 12keV
- •Noise ≤200e (50 × 10⁻³ photons @ 12keV)
- •Storage depth ≥200 images
- •Analogue readout between bunch-trains



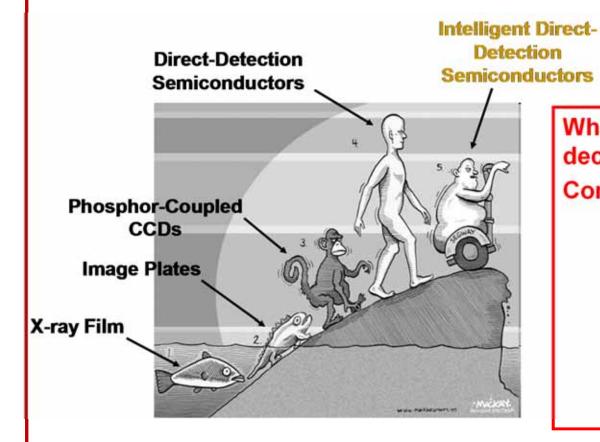






On the 10 year time scale, detectors of large format (> 10^6 pixels), wide dynamic range (> 10^4 10 keV x-rays/pix/frame), frame rates of ~100ns, and frame depths of hundreds of frames are likely feasible. If the dynamic range is reduced to ~10's of x-rays/pix/frame, frame rates can likely fall to a few 10's of ns.

Evolution of Imaging Synchrotron X-ray Detectors

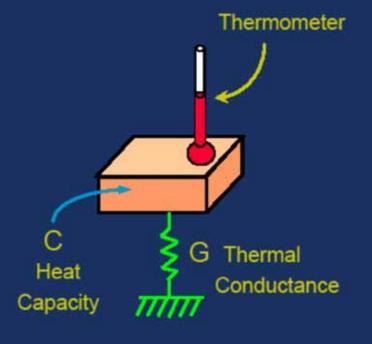


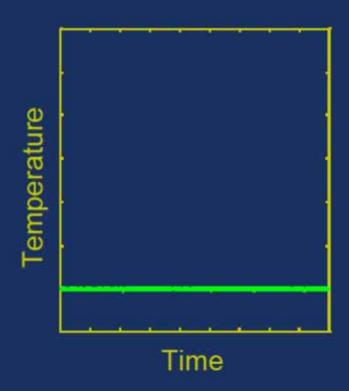
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Bolometers / Microcalorimeters

Slide from Kent Irwin of NIST, shown at SRI-2005 at ANL





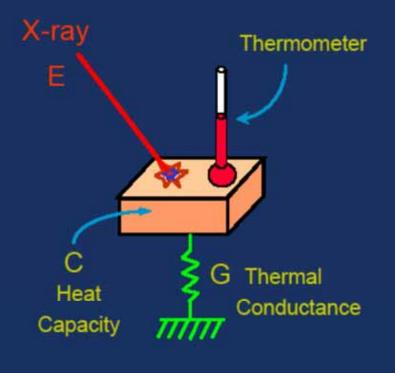


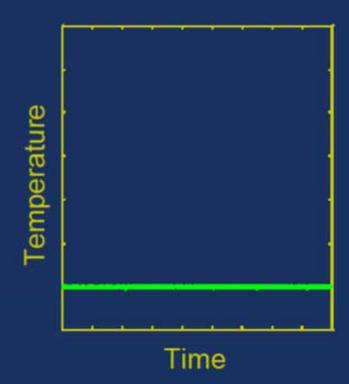
National Institute of Standards and Technology • Technology Administration • U.S. Department of Commerce



Bolometers / Microcalorimeters

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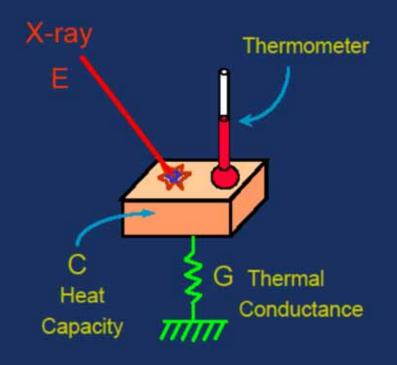
Photon

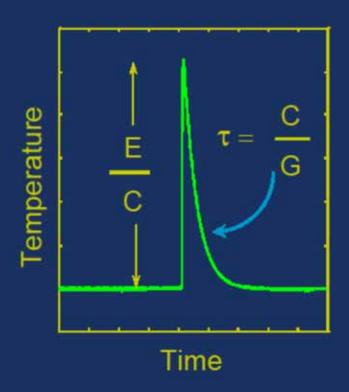
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Bolometers / Microcalorimeters

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Photon → Heat





Development possible over 5-10 years

Slide from Kent Irwin of NIST, shown at SRI-2005 at ANL

All pixels 250 µm in size...

Optimization	E	ΔE_{FWHM}	array size	Array count rate	Timescale
Best resolution	0.1 – 10 keV	3 eV	32 × 32	200 kHz	~ 3 years
Best count rate 1 keV	0.1 – 1 keV	6 eV	100 × 100	20 MHz	~ 5 years
Best count rate 10 keV	0.1 – 10 keV	20 eV	100 × 100	5 MHz	~ 5 years
Microwave	0.1 – 10 keV	5 eV	100,000	100 MHz	5 - 10 years

Can also make instruments for THz, IR, visible & UV, γ-ray



National Institute of Standards and Technology • Technology Administration • U.S. Department of Commerce



Warnings!

- 1. Difference between feasibility and reality: \$
- 2. No one detector will have all the characteristics discussed.

Cornell PAD Group

- Actively working on PAD projects at Cornell:
 - Darol Chamberlain
 - Kate Green
 - Marianne Hromalik
 - Hugh Philipp
 - Mark Tate
 - Sol Gruner
- PAD Design Collaborators:
 - Area Detector Systems Corp.
 - SLAC

- Past PAD Group Members:
 - Dan Schuette
 - Alper Ercan
 - Tom Caswell
 - Matt Renzi
 - Guiseppe Rossi
 - Sandor Barna
 - Bob Wixted
 - Eric Eikenberry
 - Lucas Koerner
- Support:
 - U.S. Dept. of Energy
 - U.S. National Inst. Health
 - U.S. National Science Found.
 - Keck Foundation



END

The ideal detector

Should have:

- 10⁹ pixels
- 1um spatial resolution
- 1eV energy resolution
- 1 fs time resolution
- count rates up to 10⁹ / pixel
- Efficient from 100eV out to 100keV
- And it should be free!

Shamelessly stolen from Peter Siddons